

# JRASET!

### International Journal for Research in Applied Science & Engineering Technology

IJRASET is indexed with Crossref for DOI-DOI: 10.22214

Website: www.ijraset.com, E-mail: ijraset@gmail.com



It is here by certified that the paper ID: IJRASET31566, entitled

Design of High gain LNA using 180nm CMOS for Wearable Devices

Network

by

#### M. Shaieena Bhanu

after review is found suitable and has been published in Volume 8, Issue IX, September 2020

in

International Journal for Research in Applied Science & Engineering Technology
Good luck for your future endeavors



ISRA Journal Impact Factor: **7.429** 









By were

Editor in Chief, iJRASET



# RASET

### International Journal for Research in Applied Science & Engineering Technology

IJRASET is indexed with Crossref for DOI-DOI: 10.22214

Website: www.ijraset.com, E-mail: ijraset@gmail.com



It is here by certified that the paper ID: IJRASET31566, entitled

Design of High gain LNA using 180nm CMOS for Wearable Devices

Network

by

S. Suvitha

after review is found suitable and has been published in Volume 8, Issue IX, September 2020

111

International Journal for Research in Applied Science & Engineering Technology
Good luck for your future endeavors



ISRA Journal Impact Factor: **7.429** 









By were

Editor in Chief, iJRASET



# JRASET!

### International Journal for Research in Applied Science & Engineering Technology

IJRASET is indexed with Crossref for DOI-DOI: 10.22214

Website: www.ijraset.com, E-mail: ijraset@gmail.com



It is here by certified that the paper ID: IJRASET31566, entitled

Design of High gain LNA using 180nm CMOS for Wearable Devices

Network

by

J. M. Mathana

after review is found suitable and has been published in Volume 8, Issue IX, September 2020

111

International Journal for Research in Applied Science & Engineering Technology
Good luck for your future endeavors



ISRA Journal Impact Factor: **7.429** 









By were

Editor in Chief, iJRASET